EAST Search History

10/596380

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	10/596380	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 20:30
L2	5	("5589694").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 20:34
L3	1	"5488000".PN.	USPAT; USOCR	OR	OFF	2007/08/12 20:31
L4	1	"5426064".PN.	USPAT; USOCR	OR	OFF	2007/08/12 20:31
L5	1	"5418389".PN.	USPAT; USOCR	OR	OFF	2007/08/12 20:31
L6	1	"5275851".PN.	USPAT; USOCR	OR	OFF	2007/08/12 20:32
L7	1	"5229625".PN.	USPAT; USOCR	OR	OFF	2007/08/12 20:32
L8	1	"5147826".PN.	USPAT; USOCR	OR	OFF	2007/08/12 20:32
L9	1	"4912061".PN.	USPAT; USOCR	OR	OFF	2007/08/12 20:33
L10	1	"4894699".PN.	USPAT; USOCR	OR	OFF	2007/08/12 20:33
L11	1	"4769686".PN.	USPAT; USOCR	OR	OFF	2007/08/12 20:33
L12	1	11 and (matrix or pixel or device or plurality or polysilicon or amorphous or silicon or polycrystalline or n-type or p-type or doped or intrinsic or overley or contact or substrate or source or drain or light or display or electrolum inescent or sensor or photo or pin or diode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 20:44
L13	5	2 and (matrix or pixel or device or plurality or polysilicon or amorphous or silicon or polycrystalline or n-type or p-type or doped or intrinsic or overley or contact or substrate or source or drain or light or display or electrolum inescent or sensor or photo or pin or diode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 20:56

EAST Search History

L14	1	3 and (matrix or pixel or device or plurality or polysilicon or amorphous or silicon or polycrystalline or n-type or p-type or doped or intrinsic or overley or contact or substrate or source or drain or light or display or electrolum inescent or sensor or photo or pin or diode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:03
L15	1	4 and (matrix or pixel or device or plurality or polysilicon or amorphous or silicon or polycrystalline or n-type or p-type or doped or intrinsic or overley or contact or substrate or source or drain or light or display or electrolum inescent or sensor or photo or pin or diode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:04
L16	1	5 and (matrix or pixel or device or plurality or polysilicon or amorphous or silicon or polycrystalline or n-type or p-type or doped or intrinsic or overley or contact or substrate or source or drain or light or display or electrolum inescent or sensor or photo or pin or diode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:05
L17	1	6 and (matrix or pixel or device or plurality or polysilicon or amorphous or silicon or polycrystalline or n-type or p-type or doped or intrinsic or overley or contact or substrate or source or drain or light or display or electrolum inescent or sensor or photo or pin or diode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:06
L18	1	7 and (matrix or pixel or device or plurality or polysilicon or amorphous or silicon or polycrystalline or n-type or p-type or doped or intrinsic or overley or contact or substrate or source or drain or light or display or electrolum inescent or sensor or photo or pin or diode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:06
L19	1	8 and (matrix or pixel or device or plurality or polysilicon or amorphous or silicon or polycrystalline or n-type or p-type or doped or intrinsic or overley or contact or substrate or source or drain or light or display or electrolum inescent or sensor or photo or pin or diode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:07

L20	1	9 and (matrix or pixel or device or plurality or polysilicon or amorphous or silicon or polycrystalline or n-type or p-type or doped or intrinsic or overley or contact or substrate or source or drain or light or display or electrolum inescent or sensor or photo or pin or diode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:07
L21	1	10 and (matrix or pixel or device or plurality or polysilicon or amorphous or silicon or polycrystalline or n-type or p-type or doped or intrinsic or overley or contact or substrate or source or drain or light or display or electrolum inescent or sensor or photo or pin or diode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:09
L22	1	11 and (matrix or pixel or device or plurality or polysilicon or amorphous or silicon or polycrystalline or n-type or p-type or doped or intrinsic or overley or contact or substrate or source or drain or light or display or electrolum inescent or sensor or photo or pin or diode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:10
L23	3	(active adj matrix adj pixel adj device) and (PIN adj diode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:11
L24	1948	257/192	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:11
L25	1622	257/200	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:11
L26	549	257/201	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:17

L27	2496	257/350	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:17
L28	490	257/359	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:17
L29	843	257/213	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:17
L30	2301	257/288	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:17
L31	219	257/381	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:17
L32	302	257/544	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:18
L33	119	257/614	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:18
L34	382	257/615	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:18

L35	1012	257/754	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/12 21:18